

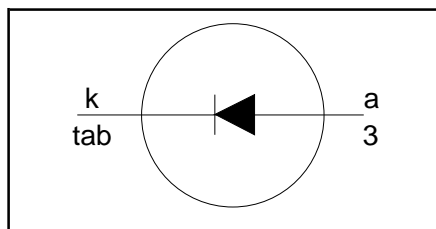
Rectifier diode ultrafast, low switching loss

BYC5B-600

FEATURES

- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

SYMBOL



QUICK REFERENCE DATA

$V_R = 600$ V
$V_F \leq 1.75$ V
$I_{F(AV)} = 5$ A
$t_{rr} = 19$ ns (typ)

APPLICATIONS

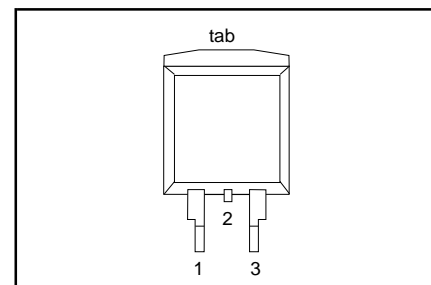
- Active power factor correction
- Half-bridge lighting ballasts
- Half-bridge/ full-bridge switched mode power supplies.

The BYC5B-600 is supplied in the SOT404 surface mounting package.

PINNING

PIN	DESCRIPTION
1	no connection
2	cathode ¹
3	anode
tab	cathode

SOT404



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	Peak repetitive reverse voltage		-	600	V
V_{RWM}	Crest working reverse voltage		-	600	V
V_R	Continuous reverse voltage		-	500	V
$I_{F(AV)}$	Average forward current	$T_{mb} \leq 110$ °C $\delta = 0.5$; with reapplied $V_{RRM(max)}$; $T_{mb} \leq 89$ °C ¹	-	5	A
I_{FRM}	Repetitive peak forward current	$\delta = 0.5$; with reapplied $V_{RRM(max)}$; $T_{mb} \leq 89$ °C ¹	-	10	A
I_{FSM}	Non-repetitive peak forward current.	$t = 10$ ms $t = 8.3$ ms sinusoidal; $T_j = 150$ °C prior to surge with reapplied $V_{RWM(max)}$	-	40 44	A A
T_{stg}	Storage temperature		-40	150	°C
T_j	Operating junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base		-	-	2.5	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	minimum footprint, FR4 board	-	50	-	K/W

¹ it is not possible to make connection to pin 2 of the SOT404 package

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ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 5\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	1.4	1.75	V
		$I_F = 10\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	1.75	2.2	V
I_R	Reverse current	$I_F = 5\text{ A}; V_R = 600\text{ V}$	-	2.0	2.8	V
		$V_R = 500\text{ V}; T_j = 100\text{ }^\circ\text{C}$	-	9	100	μA
t_{rr}	Reverse recovery time	$I_F = 5\text{ A}; dI_F/dt = 500\text{ A}/\mu\text{s}; V_R = 400\text{ V}$	-	0.9	3.0	ns
t_{rr}	Reverse recovery time	$I_F = 5\text{ A}; dI_F/dt = 500\text{ A}/\mu\text{s}; V_R = 400\text{ V}; T_j = 125\text{ }^\circ\text{C}$	-	19	-	ns
I_{rrm}	Peak reverse recovery current	$I_F = 5\text{ A}; V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 125\text{ }^\circ\text{C}$	-	25	30	ns
V_{fr}	Forward recovery voltage	$I_F = 10\text{ A}; dI_F/dt = 100\text{ A}/\mu\text{s}$	-	8	11	A
			-	9	11	V

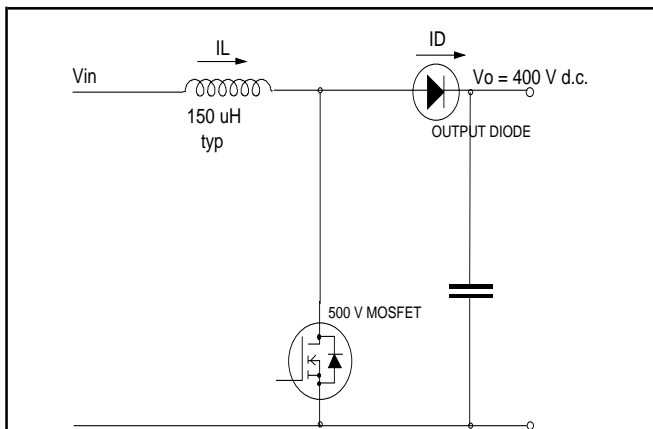


Fig.1. Typical application, output rectifier in boost converter power factor correction circuit. Continuous conduction mode, where the transistor turns on whilst forward current is still flowing in the diode.

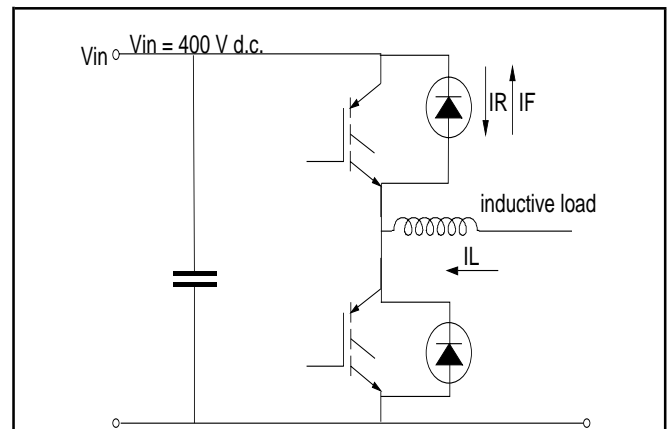
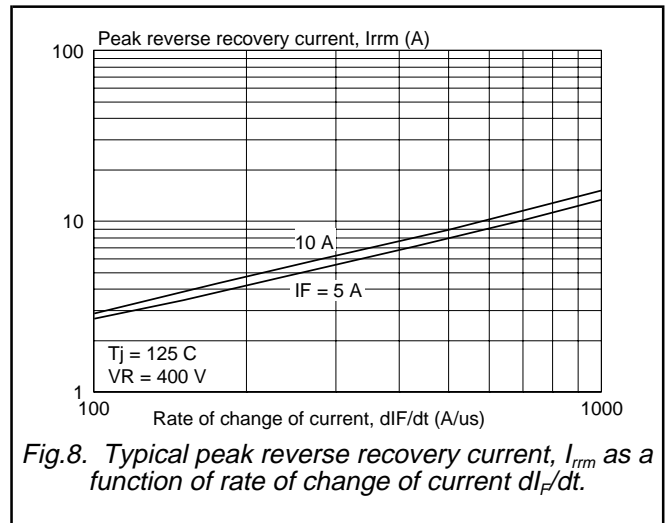
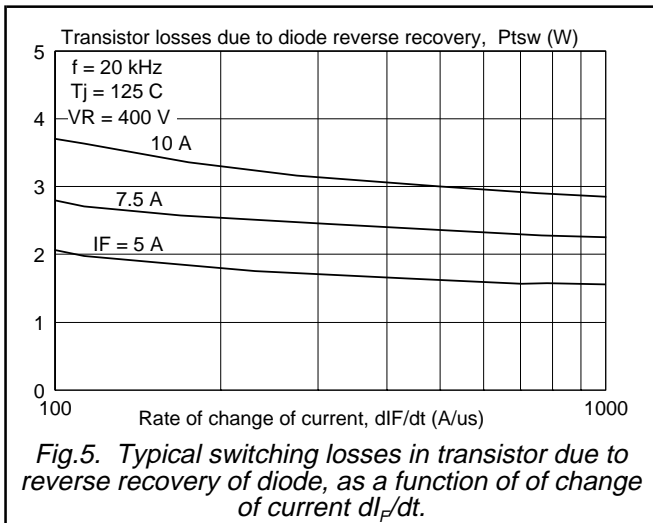
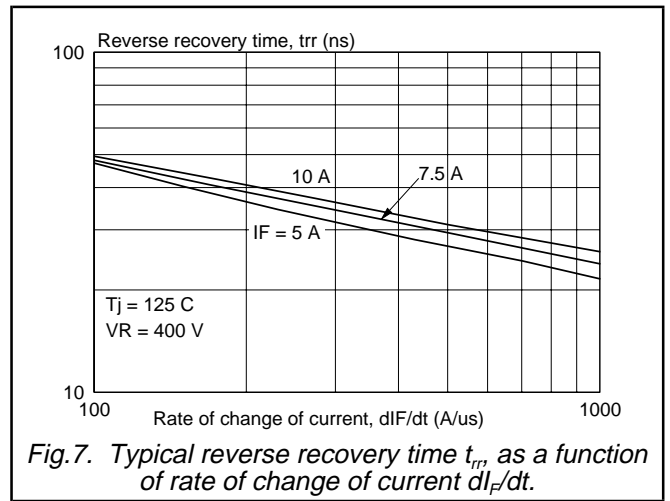
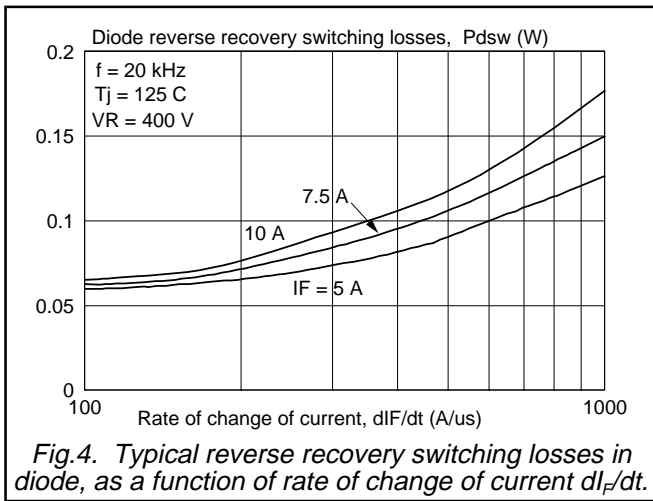
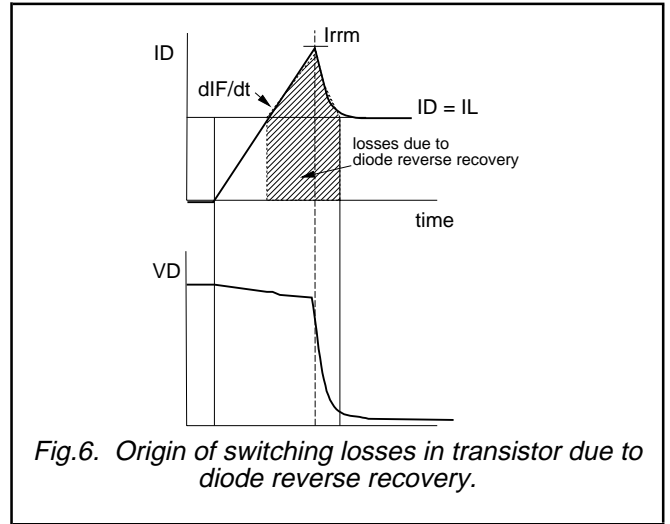
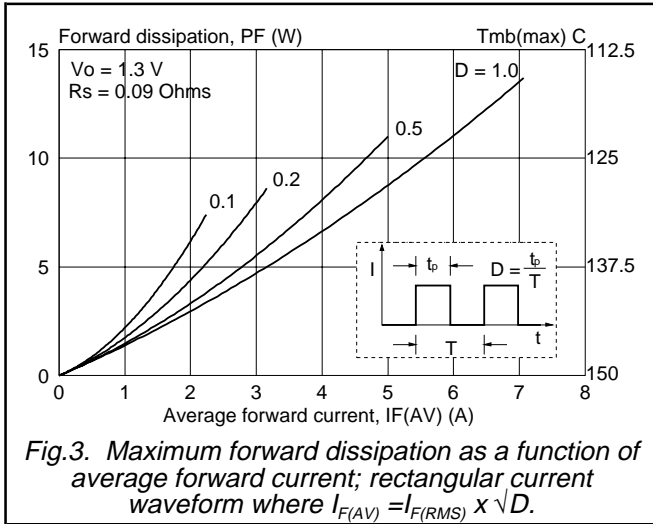


Fig.2. Typical application, freewheeling diode in half bridge converter. Continuous conduction mode, where each transistor turns on whilst forward current is still flowing in the other bridge leg diode.

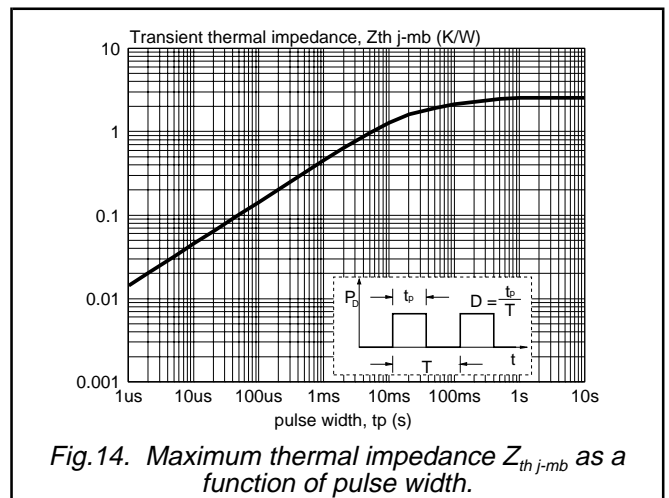
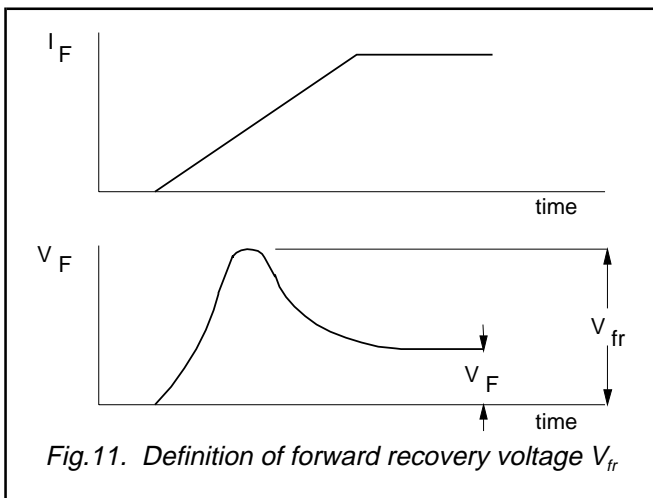
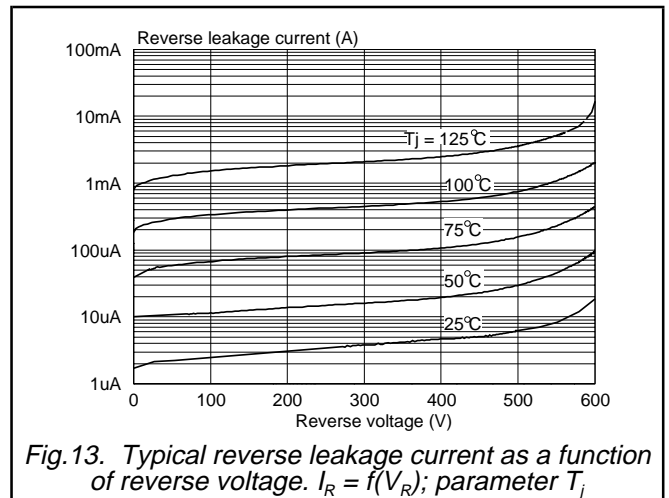
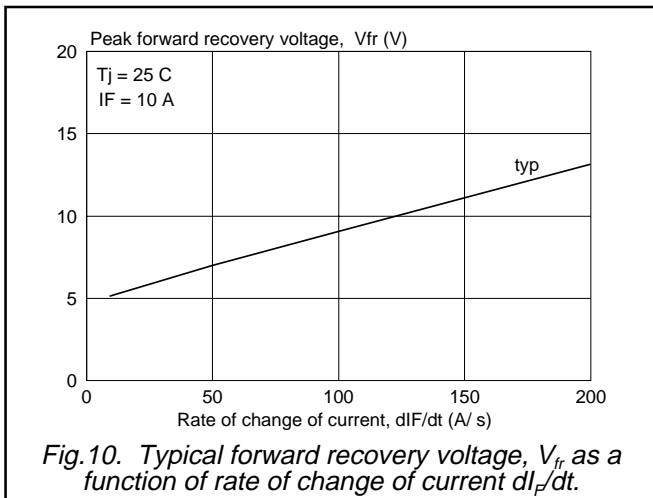
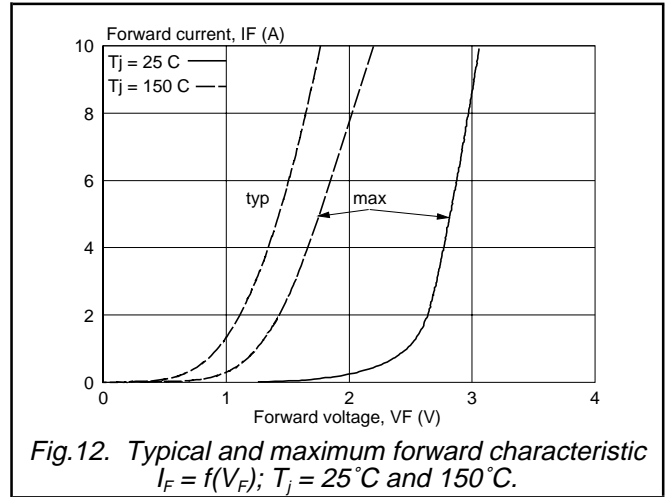
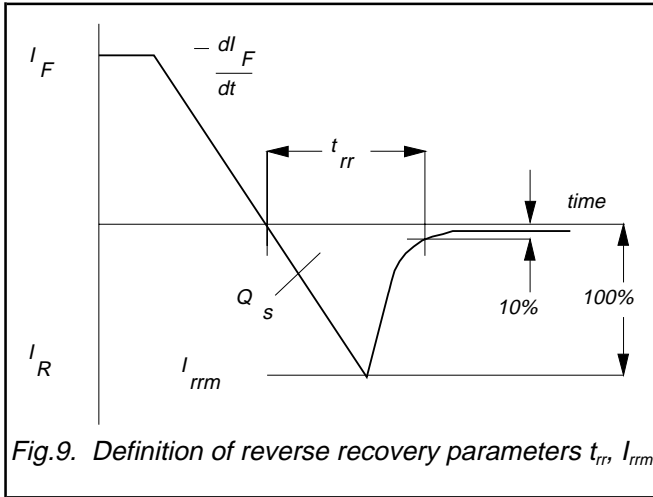
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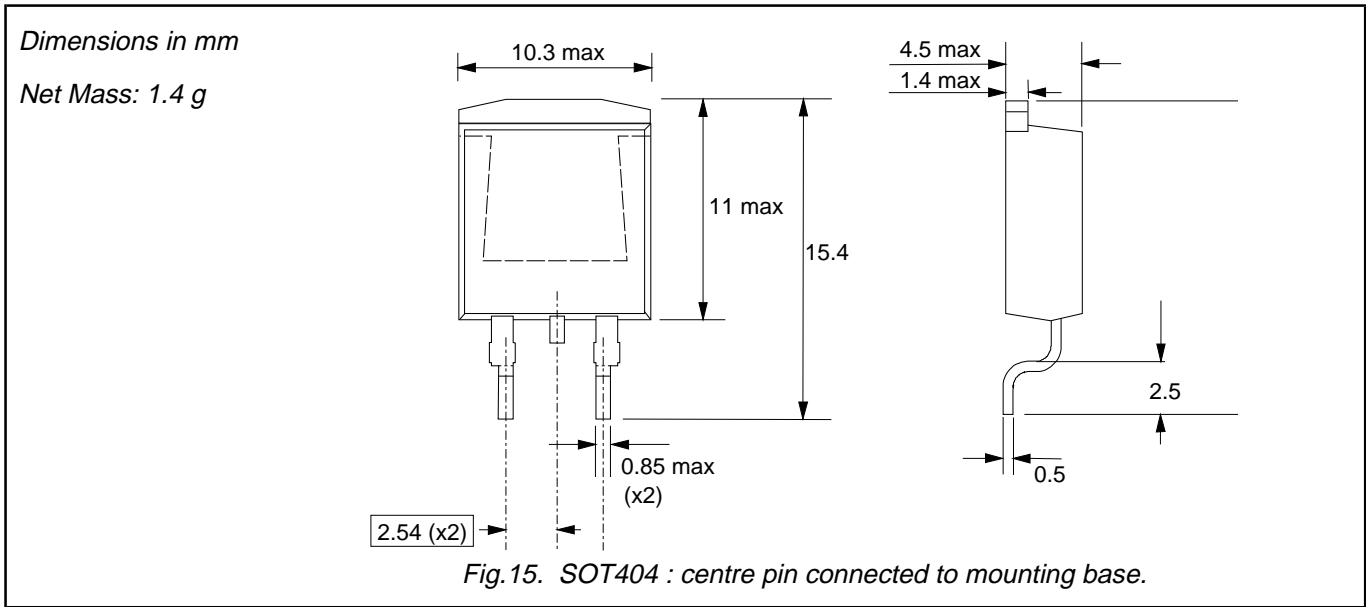
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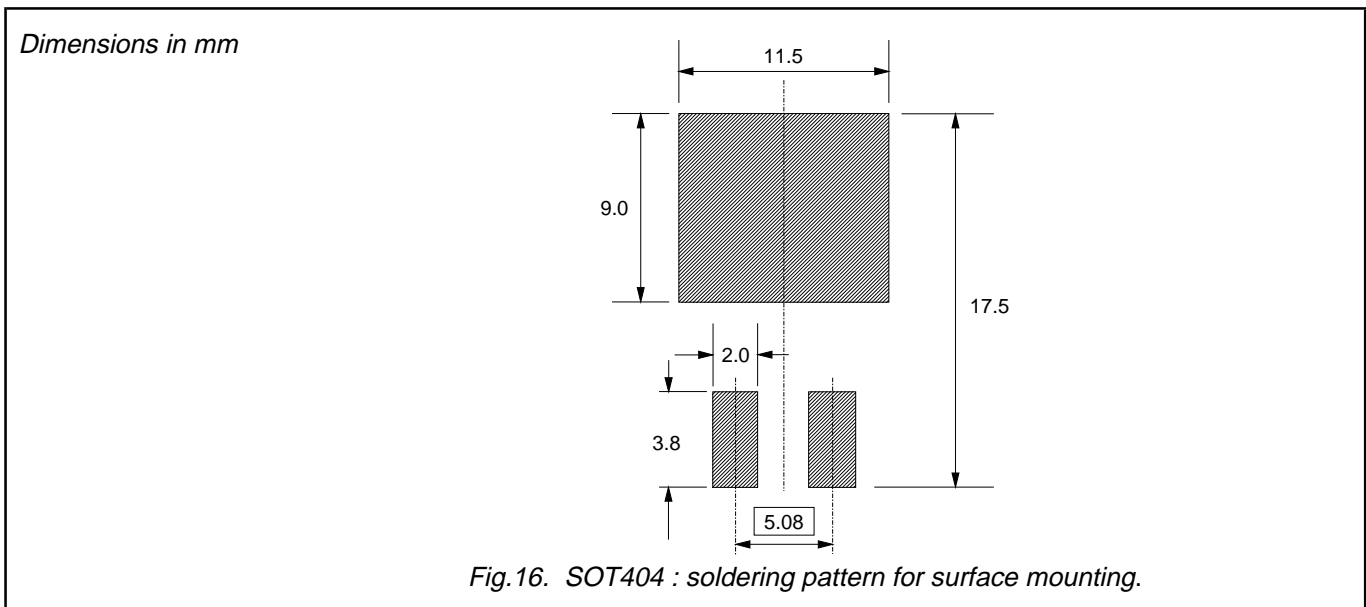
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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

- 1. Epoxy meets UL94 V0 at 1/8".

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BYC5B-600**DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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